

# 查询"2PD602AQL 供应表 2PD602AQL; 2PD602ARL; 2PD602ASL

### 50 V, 500 mA NPN general-purpose transistors

Rev. 01 — 27 October 2008

**Product data sheet** 

#### **Product profile** 1.

#### 1.1 General description

NPN general-purpose transistors in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

#### Table 1. **Product overview**

Type number <sup>[1]</sup>	Package	PNP complement	
	NXP	JEDEC	
2PD602AQL	SOT23	TO-236AB	-
2PD602ARL	RL		2PB710ARL
2PD602ASL			2PB710ASL
2PD602AQL/DG	SOT23	TO-236AB	-
2PD602ARL/DG		2PB710ARL/DG	
2PD602ASL/DG			2PB710ASL/DG

[1] /DG: halogen-free

#### 1.2 Features

- General-purpose transistors
- Three current gain selections
- AEC-Q101 qualified
- Small SMD plastic package

#### **1.3 Applications**

General-purpose switching and amplification

#### 1.4 Quick reference data

#### Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	50	V
I <sub>C</sub>	collector current		-	-	500	mA



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Table 2.	Quick reference data .	continued				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 10 V; I <sub>C</sub> = 150 mA	<u>[1]</u>			
	h <sub>FE</sub> group Q		85	-	170	
	h <sub>FE</sub> group R		120	-	240	
	h <sub>FE</sub> group S		170	-	340	

### 2. Pinning information

Table 3.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	base	<b>—</b>	_
2	emitter		3
3	collector		1-1-2
			sym021

### 3. Ordering information

Type number <sup>[1]</sup>	Package					
	Name	Description	Version			
2PD602AQL	-	plastic surface-mounted package; 3 leads	SOT23			
2PD602ARL						
2PD602ASL						
2PD602AQL/DG	-	plastic surface-mounted package; 3 leads	SOT23			
2PD602ARL/DG						
2PD602ASL/DG						

### 4. Marking

Table 5. Marking codes	
Type number	Marking code <sup>[1]</sup>
2PD602AQL	SH*
2PD602ARL	SG*
2PD602ASL	SF*

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Table 5.	Marking	codes	continued
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Type number	Marking code <sup>[1]</sup>
2PD602AQL/DG	SX*
2PD602ARL/DG	SW*
2PD602ASL/DG	SV*

[1] \* = -: made in Hong Kong

\* = p: made in Hong Kong

\* = t: made in Malaysia

\* = W: made in China

### 5. Limiting values

#### Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	60	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	50	V
$V_{\text{EBO}}$	emitter-base voltage	open collector	-	5	V
I <sub>C</sub>	collector current		-	500	mA
I <sub>CM</sub>	peak collector current	single pulse; $t_p \leq 1 ms$	-	1	A
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms	-	200	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	<u>[1]</u> _	250	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-55	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

### 6. Thermal characteristics

Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	<u>[1]</u> _	-	500	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

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### 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = 60 \text{ V}; I_E = 0 \text{ A}$		-	-	10	nA
		$V_{CB} = 60 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 \text{ °C}$		-	-	5	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 4 \text{ V}; \text{ I}_{C} = 0 \text{ A}$		-	-	10	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = 10 \text{ V};$ $I_{C} = 500 \text{ mA}$	<u>[1]</u>	40	-	-	
	h <sub>FE</sub> group Q	$V_{CE} = 10 \text{ V};$ $I_{C} = 150 \text{ mA}$	<u>[1]</u>	85	-	170	
	h <sub>FE</sub> group R	V <sub>CE</sub> = 10 V; I <sub>C</sub> = 150 mA	<u>[1]</u>	120	-	240	
	h <sub>FE</sub> group S	V <sub>CE</sub> = 10 V; I <sub>C</sub> = 150 mA	<u>[1]</u>	170	-	340	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{\rm C}$ = 300 mA; $I_{\rm B}$ = 30 mA	<u>[1]</u>	-	-	600	mV
f <sub>T</sub>	transition frequency	$V_{CE} = 10 V;$ $I_{C} = 50 mA;$ f = 100 MHz	[1]				
	h <sub>FE</sub> group Q			140	-	-	MHz
	h <sub>FE</sub> group R			160	-	-	MHz
	h <sub>FE</sub> group S			180	-	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 V;$ $I_E = i_e = 0 A;$ f = 1 MHz		-	-	15	pF

[1] Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ .

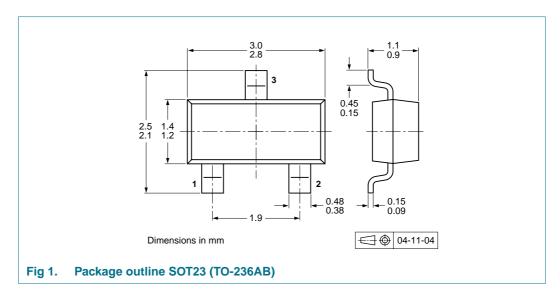
### 8. Test information

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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### 9. Package outline



### **10. Packing information**

#### Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number <sup>[2]</sup>	Package	Description	Packing	g quantity
			3000	10000
2PD602AQL	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235
2PD602ARL				
2PD602ASL				
2PD602AQL/DG	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235
2PD602ARL/DG				
2PD602ASL/DG				

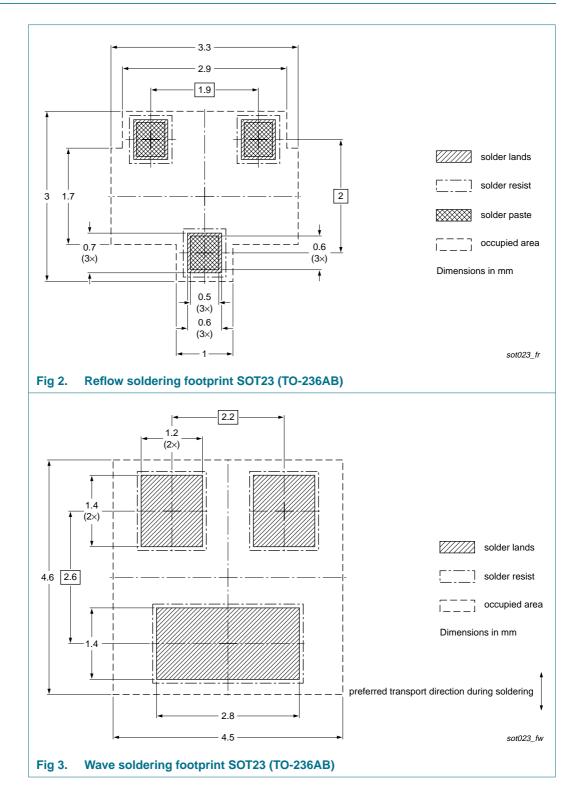
[1] For further information and the availability of packing methods, see <u>Section 14</u>.

[2] /DG: halogen-free

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### **11. Soldering**



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### 12. Revision history

Table 10. Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
2PD602AXL_1	20081027	Product data sheet	-	-	

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### **13. Legal information**

#### 13.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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[2] The term 'short data sheet' is explained in section "Definitions".

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